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High resolution thermoplastic rapid manufacturing using injection moulding with SU-8 based silicon tools

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The present work focuses on developing cost-efficient, fast and precise tooling for prototyping and small-series manufacture of polymer chips using injection moulding. Exchangeable mould inserts were manufactured on thick silicon wafers patterned using SU-8 negative epoxy-based resist. First masters with feature size from a few tens to hundreds of micrometers were produced in SU-8 photoresist by contact photolithography. Polypropylene (PP), cyclo-olefin-co-polymer (COC) and polymethylmethacrylate (PMMA) were used as the injection moulding materials. A study of the PP parts was carried out using scanning mechanical microscopy (SMM) and scanning electron microscopy (SEM). In addition, submicronic features (500 nm) were replicated in PP from a tool patterned by e-beam lithography.

1. Introduction

While manufacturing durable moulds in metals and alloys is the mainstream for micro-replication technologies such as micro-injection moulding, it requires rather complex and time consuming processes, and it is therefore expensive. The need for accessible, flexible and low-cost tooling is particularly relevant for prototyping and manufacturing small series of polymeric parts, especially at the laboratory level. This involves multiple challenges. First, the tool must be produced rapidly and at low cost. Second, the machinability of the insert material and especially the quality of inner surfaces such as surface roughness and sidewall draft angle are important for good replication and demoulding, particularly for smaller features where interfacial effects become dominant with the increase of surface/volume ratio. Third, the tool needs to be mounted easily on the injection moulding machine and exchanged rapidly. Fourth, it must be robust enough to survive a few tens to a few hundreds cycles to produce parts in sufficient numbers for testing. Additional attributes required for mould insert are thermal shock resistance and thermal conductivity. A further challenge is to develop a process that is extendable in term of pattern features to submicronic and nanometric scales.

One solution which is developed in this work is to use silicon wafers as exchangeable mould inserts that are patterned by clean room technologies. More specifically, we developed a process to manufacture micronic and submicronic SU-8 features on silicon based tools for micro-injection moulding.

Silicon has been traditionally the major material used in MEMS. Defining the patterns on mould insert using materials and techniques used in clean room for well-established microelectronics and microsystem applications (mainly MEMS and MOEMS), has a number of advantages. In particular, contact photolithography enables the collective manufacture of microstructures into a number of photoresists, i.e. parallel pattern transfer from mask into resist, with any pattern geometry in 2D, relatively high resolution (down to a few micrometers), well-defined contours and smooth sidewalls. Electron beam lithography is a direct write technique which allows manufacturing submicronic to nanometric features in electron beam sensitive resists.

SU-8 is a negative tone photosensitive resist optimized for ultraviolet photolithography and the most popular resist in microsystem technologies. Its very high optical transparency and high contrast for light above 360 nm wavelength make it ideally suited for applications with high aspect ratio (ratio of height over width) and nearly vertical sidewalls in very thick layers [1]. It has good qualities for a structural material, is mechanically strong when cross-linked and its epoxy base provides the chemical and thermal stability for the patterned structures. SU-8 resist is also known to be electron beam sensitive and therefore can be patterned using electron-beam lithography. A minimum linewidth of 250 nm was reported by Bogdanov [2]. The advantage of SU-8

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resist is therefore that it can be used with both standard photolithography and e-beam lithography, allowing to extend the process range developed with SU-8 to submicronic feature size. It also allows potentially employing mix and match technology (hybrid fabrication) with the larger features being produced by photolithography and the smallest ones by electron-beam lithography on the same wafer.

Edwards et al. was the first to demonstrate the use of SU-8/Si mould inserts for injection moulding. They produced 8–22 replicas in two common thermoplastic polymers, amorphous polycarbonate (PC) and semi-crystalline polypropylene (PP), using metallized SU-8 patterns on silicon wafers as inserts [3]. More recently, Steigert et al. fabricated polymer replicas of COC using an epoxy master with Al powder made by casting without any degradation of the pattern for more than 200 cycles [4]. Finally, more than 300 replicas of COC were produced by Hansen et al. using photolithographically patterned SU-8 on robust nickel mould insert base [5].

We report here on our processes for manufacturing SU-8/Si mould inserts and first experiments in using them for injection-moulding of polymer parts. Polypropylene (PP) was used for the test structures as it is one of the most commonly used polymer for injection moulding due to its good fluidity at high temperature. A study of PP replicas was conducted using scanning mechanical microscopy (SMM) and scanning electron microscopy (SEM). Injection moulding of microstructures was then carried out in two thermoplastic polymers largely employed in the manufacture of microfluidic devices, PMMA and COC. Finally, we investigated mould making with submicronic patterning using electron beam lithography and its replication in PP.

2. Experimental

2.1. Patterned Si mould insert and tool

2.1.1. SU-8 patterning for mould insert

Ideally producing a mould insert with slightly inclined mould walls, that is an inward taper of a few degrees from the base to the top (positive draft angle), facilitates demoulding of the injected parts. However, realizing such sloped sidewalls with SU-8 proved very difficult so the objective was to obtain structures with sidewalls as vertical as possible. Additional challenges concern a good adherence of the SU-8 micropatterns to the silicon base plate which might be affected by various factors such as: (1) internal stress build-up (for which SU-8 is known) during processing, which includes effect of mismatch between thermal expansion coefficient of crosslinked SU-8/Si substrate ($50 \times 10^{-6} \text{ K}^{-1}$ vs. $4.68 \times 10^{-6} \text{ K}^{-1}$) causing adhesion loss between SU-8 and Si; (2) large shear forces exerted on the SU-8 microstructures by the flow of melted polymer during the filling of the cavity in the injection step; (3) tearing of the patterns that may occur due to the friction forces between the mould insert and polymer replica during the demoulding step.

The adherence of the SU-8 patterns is improved by using a two-layer process. A first layer of SU-8 (approximately 50 μm thick) was spin-coated on the virgin wafer and blank-exposed on its whole surface. The second layer of SU-8, which defines the patterns, was spin coated with the desired thickness (from 25 μm to 100 μm thick) on top of the first layer, and patterned by contact UV photolithography. The first SU-8 unpatterned coating served to increase the adhesion for the second SU-8 layer in which the micrometric-size patterns were formed. Preliminary experiments without this first layer revealed systematic destruction of the patterns of the mould insert during the demoulding. Then, the adhesion of each SU-8 layer is increased by exposing the surface to oxygen plasma before dispensing the resist (i.e. the silicon substrate for the first SU-8 layer step and the first SU-8 layer for the second SU-8 layer step). Finally, both SU-8 layers are exposed

and polymerized by following strictly the SU-8 datasheet corresponding to the SU-8 2075 formulation [6]. In particular, the UV exposure is conducted using the recommended long pass filter (PL-360-LP from Omega Optical) to obtain vertical sidewalls. Finally, a hard bake (200 °C during 1 h) is added to ensure further crosslinking so that SU-8 properties do not change in actual use during the injection moulding process. Additionally, the resist pattern lines and sidewalls obtained with the lithographic process were smooth and suitable for good replication.

The layout of the mask for the trial mould was made in such a way that the patterns were evenly distributed over the surface. The ridges (inverse of channels) were 30 mm long and their width covered the range: 25, 50, 100, 150, 200, 250, 300 to 400 μm . They were ended by pillars (inverse of reservoirs) of 2 mm diameter. The maximum aspect ratio investigated in these experiments was 4 obtained with a 90 μm thick SU-8 photoresist and 25 μm feature size. The distance separating the ridges was chosen large enough (3 mm) so that the polymer could flow well during injection moulding.

The overall time used to process a SU-8/Si mould insert with photolithography was around 10 h which encompasses patterning the optical mask by laser pattern generator, the two-layer SU-8 process with oxygen plasma treatment, the UV exposure step followed by hard bake. In comparison, for feature size above 100 μm , the manufacture of such an insert in metal by milling would take around 1 day including CAD software and CNC machining. However, the minimum feature size on the SU-8 mould insert was 25 μm , and it could be further reduced to a few micrometers still using standard contact photolithography, which would be very difficult to achieve, if not impossible, using a standard micromilling process. The manufacture of such silicon mould insert for feature size in the range 100 μm – to a few micrometers is therefore very competitive with mechanical micromachining in term of time to produce the insert. In addition, the clean room process can be extended further towards smaller dimensions but at the cost of time.

Concerning the generation of submicronic features, patterning was performed using electron-beam lithography in SU-8 resist, which allowed reaching a resolution down to 100 nm. A 600 nm SU-8 resist layer was spin-coated on a thick silicon wafer using SU-2002 resist (Microchem) mixed with its thinner in a ratio 1:0.5, followed by a baking step at 95 °C during 1 min. The electron beam exposure was conducted with a Raith E-Line system. The best doses (around 2 $\mu\text{C}/\text{cm}^2$) were selected depending of the size and of the pitch of the features. The patterning speed was 20 min/ mm^2 for feature size ranging from 1 μm to 100 nm. After a postbake of 2 min at 95 °C, the resist was developed in Propylene Glycol Methyl Ether Acetate (PGMEA, same developer used for the photolithographic process) during 10 min.

Producing a mould insert using electron beam lithography employs a direct patterning method (without a mask). It has the advantage of using a standard tool developed for generation of the micronic, submicronic, and nanoscale geometries, allowing flexible pattern design, highly automated and precisely controlled operation (like accurate positioning). Though relatively slow, the throughput of electron beam lithography is competitive with proximal probe-based writing techniques such as atomic force microscopy (AFM), scanning tunneling microscopy (STM), dip-pen lithography (DPL), near-field scanning optical microscopy (NSOM), and apertureless near-field scanning optical microscopy (ANSOM), especially if they are used in a non parallel scheme.

2.1.2. Mould tool and inserts

The mould tool that was developed consists of mould base plates screwed to a standard steel mould tool of a conventional injection moulding machine (see paragraph on injection moulding) so that they could be mounted and changed easily (Figs. 1 and 2). In

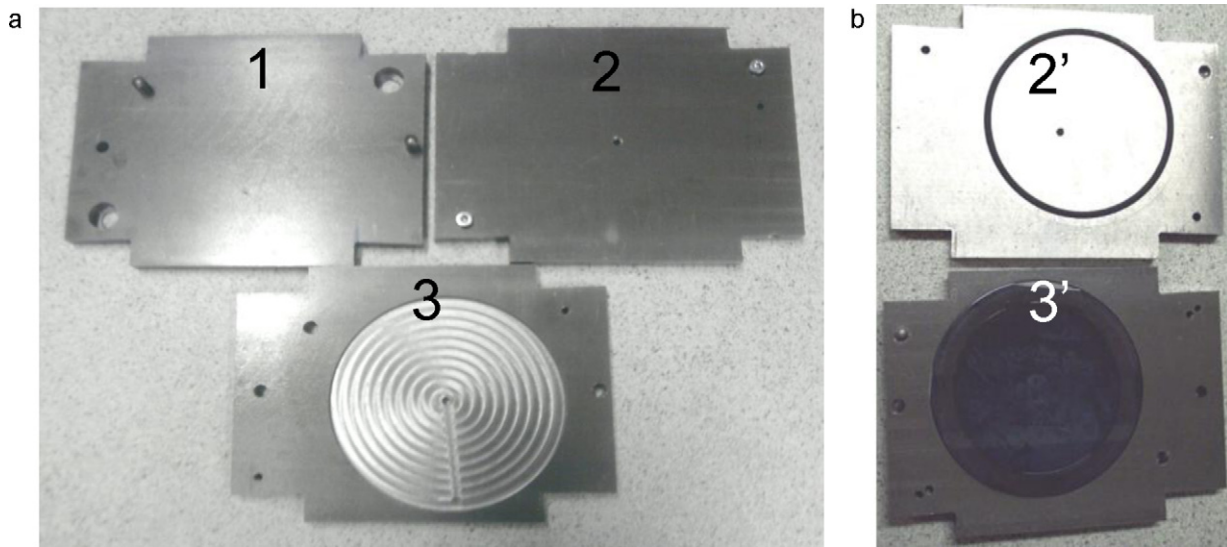


Fig. 1. Photographs corresponding to the outer and inner views (a and b, respectively) of the 3 mould tool plates fabricated to accommodate the exchangeable SU-8/Si mould insert; (a) outer views of: plate # 1, back plate to be fixed on the mould base; plate #2, top plate which closes the mould insert cavity, has a hole in the middle (gate of 2 mm) and is screwed to plate # 3; plate #3: bottom plate with grooved circular cavity to receive the silicon insert. (b) Inner views of: plate # 2', back side of plate #2 with O-ring to close the mould insert cavity; plate #3', same as plate #3 with SU-8/Si mould insert in place.

one of the plate, a circular cavity was mechanically machined to receive an interchangeable silicon wafer as a mould insert. This base plate supports the micro-structured SU-8/Si mould insert and reinforces its mechanical stability.

In the first set of experiments (PP with test structures), three-inch (400 μm thick) wafers were used as mould insert substrates. The brittleness of the silicon was not an issue when closing the mould as it closes not on the fragile silicon wafer insert but on the metallic robust mould base. However, resistance of the wafer to plastic flow and compression during injection of the polymer was an issue so the thin silicon wafer was glued (with loctite 430) to a metallic plate of same radius, which was itself screwed in one of the brass back plates to avoid movement (lifting). However, this set-up had the disadvantage of not allowing an exchange of the silicon wafers flexible enough. The mould insert tool was therefore redesigned to accommodate easily exchangeable thick and flat silicon substrates (1.5 mm-thick double-sided polished 4-in. silicon wafers) as mould inserts and eliminate the additional step of glueing or screwing used in the first set-up. The new set-up consists of three plates (numbered 1–3 in Fig. 1a and 2' and 3' in

Fig. 1b) that could be maintained inside the mould cavity by the locking mechanism (using a rubber O-ring) of the injection moulding machine. When demoulding parts, Plates 2/2' and 3/3' are removed. Possibility for variation of thickness of the replica was also included by placing the patterned silicon substrate on interchangeable steel plates or silicon wafers of the same radius.

2.2. Micro-injection moulding

2.2.1. Materials

Polypropylene (PP), a semi crystalline polymer, was chosen for the first injection moulding tests because it is known for its good fluidity and replication ability. We used two different grades, a heterophasic copolymer (Moplen EP548 N from Basell) and one polypropylene random copolymer, modified by ethylene (PP-RA12MN40 from Sabic[®]). Other polymers investigated in this work were two common optically clear amorphous thermoplastic polymers used as substrates in bio MEMS applications, COC and PMMA. We chose two grades, COC[®] Topas 8007 (from Ticona GmbH) and Plexiglass[®], 6N (from Evonik Degussa GmbH). Table 1

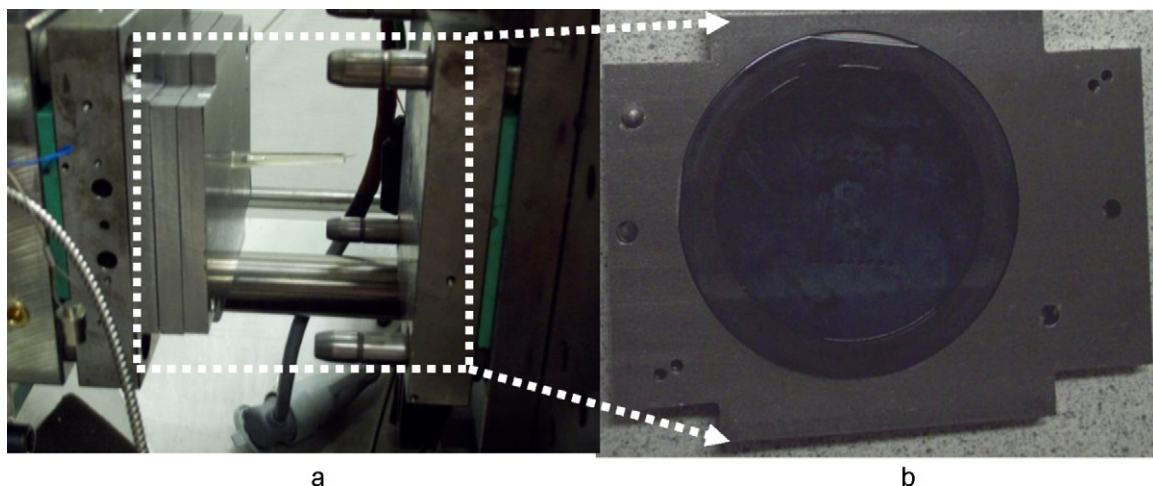


Fig. 2. (a) Photographs of the opened mould tool base with the cavity defined by the steel plates closed (on the left of the picture); a transparent PMMA sprue can be seen sticking out of this closed cavity. (b) Mould plate #3 with the SU-8/Si mould insert placed on it (picture similar to picture #3').

Table 1

Material properties of polymers (from datasheets of manufacturers) used for injection moulding along with characteristics of SU-8 photoresist [7].

Material properties	PP (Moplen EP548 N, Basell)	PP (RA12MN40, Sabic)	COC (Topas [®] 8007, Ticona GmbH)	PMMA (Plexiglass [®] , 6N, Evonik Degussa GmbH)	SU-8 (Microchem)
Mass density (g/cm ³)	0.9	0.9	1.02	1.19	1.19
Modulus (MPa)	1400	1200	2600	3200	4020
Tensile test-stress at yield (MPa)	27	32	63	67	34
Strain at break (%)	>50	>50	10	3	Data not available
Charpy impact strength notched (kJ/m ²) at 23 °C	8	3.3	20	20	Data not available
Glass transition temperature T_g for amorphous regions (°C)	Data not available	Data not available	78	99	200
Coefficient of linear thermal expansion ($10^{-6}K^{-1}$)	Data not available	Data not available	70	80	50
Melt flow index (MFI) (g/10 min)	[230 °C/2.16 kg]: 12	[230 °C/2.16 kg]: 40	[260 °C/2.16 kg]: 32	[230 °C/3.8 kg]: 12	Data not available

summarizes the properties of the thermoplastic polymer grades used in the injection moulding experiments.

2.2.2. Injection moulding

Injection moulding was conducted using an Arburg[®] Allrounder (220S/150-35) which is not optimized for micromoulding. The diameter of the plastification screw is 15 mm. The machine allows a maximum closing strength force of 50 kN and a maximum injection rate of 760 mm/s. The thermoplastic polymers were injected in the mould through an injection gate of 2 mm. The tests were carried out starting with the standard conditions recommended by the manufacturers of the polymers. The parameters varied to optimize injection moulding of the parts were the volume dosage, melt temperature, and mould temperature.

The volume dosage was first determined to fill the volume of the mould cavity (on the order of 7 cm³ of material). The melt temperature was first varied stepwise (in steps of 10 °C) to optimize the filling of the microfeatures of the mould insert cavity before solidification of the polymer melt occurs. In order to overcome flow resistance, high injection speed and high injection pressure are preferred, since the resulting high shear rate is good for viscous heating and decreasing polymer viscosity. The injection rate was increased progressively up to its final value set close to the maximum value. The injection pressure varied stepwise (in steps of 10 MPa) up to its final value, which was high though not at the maximum to minimize compression force on the silicon mould insert. An appropriate holding time at constant pressure was selected to ensure proper packing of the polymer in the microcavities of the mould insert. Good filling was obtained for PP with a mould at room temperature whereas the replication quality was improved for COC and PMMA replicas by injecting into a heated mould so that the injected melt does not freeze prematurely on the walls of the microcavity. After solidification of the polymer part inside the mould upon cooling, the replica is manually separated from the mould for the three polymers. The optimized values of the moulding parameters for injecting the various polymers with our mould inserts are summarized in Table 2.

Table 2Parameters of injection utilized in the injection moulding trials conducted on the Arburg[®] Allrounder (220S/150-35) machine.

Material	PP (Moplen EP548N, Basell)	PP (RA12MN40, Sabic)	COC (8007, TOPAS [®])	PMMA (Plexiglass [®] , 6N, Evonik)
Injection temperature (°C)	230	220	265	220
Flow rate (cm ³ /s)	22	22	20	22
Holding pressure (MPa)	80	180	180	120
Holding time (s)	10	10	10	10
Mould temperature (°C) during injection	25	25	90	60
Mould temperature (°C) during demoulding	25	25	~75	~45

3. Results and discussions

3.1. Topography of PP test replicas

Polymers parts of 500 μm thickness were produced in PP (Basel) using a SU-8/Si mould insert with a patterned SU-8 layer of 50 μm thickness (maximum aspect ratio of structures of 2). To assess the filling of the SU-8/Si mould insert and the dimensional and geometrical quality of replication, 2D profile measurements were carried out on the PP replicas of using scanning mechanical microscopy (SMM). The apparatus used is a tactile profilometer with a conical probe in diamond with a tip radius of 2 μm and a cone angle of 45° [8].

The evolutions of the channel profiles of the injected PP replicas were recorded along the XX direction. The recessed profiles of the replica were quasi-equivalent to the nominal inverted profile of both studied inserts for channel widths between 100 μm and 500 μm. This could not be verified for channels with width lower than 80 μm as the tip of the SMM probe was too large to enter into them. Fig. 3 illustrates some graphs produced with lines with different widths.

One needs to point out that the sloped shapes of the cavity sidewalls observed in Fig. 3 are due to the conical shape of the tactile probe (i.e. probe convolution effect). In reality these wall profiles are almost vertical as will be seen on the SEM pictures of Figs. 7–10 (see Section 3.3).

The dimensions (width and depth) of channels of the replicas produced in PP (Basel) were measured on a batch of ten pieces at two different locations on the chip in the middle of the channel length and at one extremity of the channel length (just before the reservoir). The depth value was measured with SMM whereas the top and bottom widths were measured optically at the focal plane of the microscope.

The results of the average size of the channels on the ten replicated pieces are gathered in Table 3a and b for the narrowest and largest channels (of nominal dimensions $h = 25 \mu\text{m}$; $e = 25 \mu\text{m}$ and $h = 400 \mu\text{m}$; $e = 25 \mu\text{m}$, respectively).

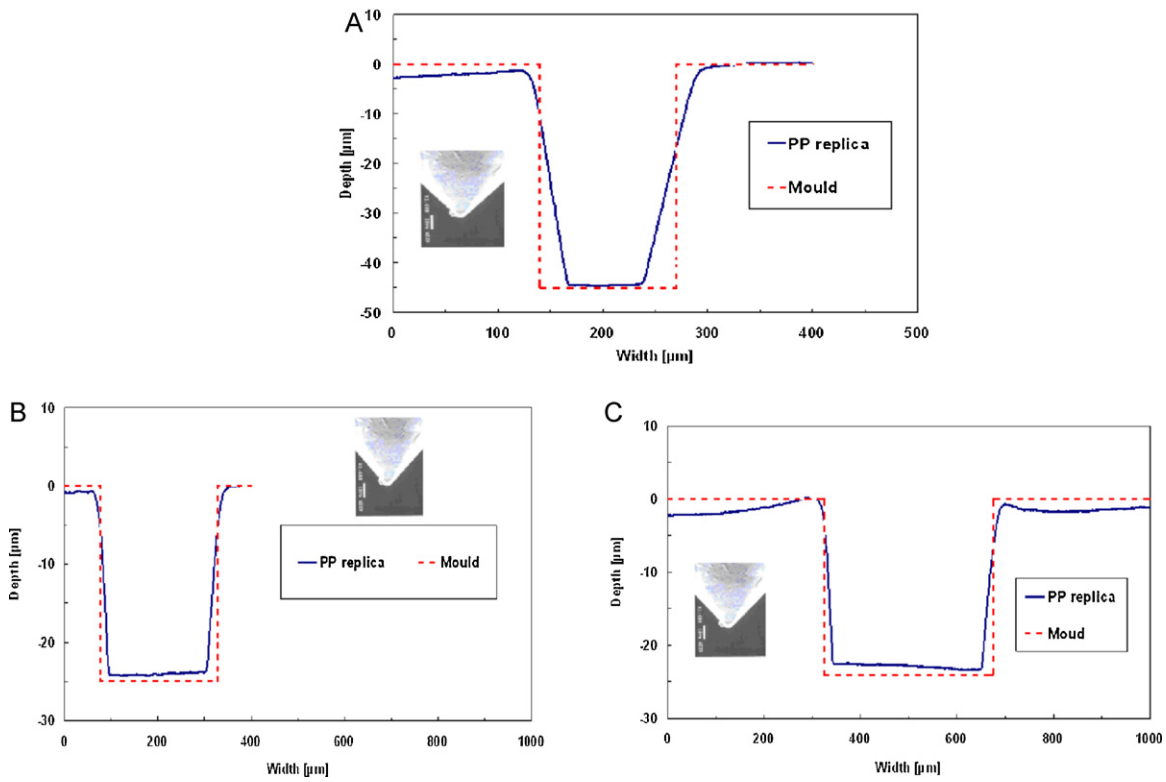


Fig. 3. Comparative 2D profiles of the topography of the nominal profile mould insert (inverted data) and its PP replicas corresponding to channel widths of 125 μm (a), 250 μm (b) and 350 μm (c) recorded in the X-X direction. An image of the tip of the SMM probe used, at the same scale, is also inserted as an inset.

3.2. Roughness of SU-8/Si mould insert and PP test replicas

Roughness measurements were carried out using a mechanical profilometer (Tencor – Alpha Step IQ) with a diamond tip of 5 μm radius operated with a scanning speed of 5 $\mu\text{m}/\text{s}$ on a length of 1 mm inside and outside the reservoir pattern of 2 mm diameter on the mould insert and replicas produced in PP (Basel). Two different

Table 3

Average depth and widths (h , e_1 and e_2 defined, respectively, as indicated in Fig. 4), of the channels located at the middle and extremity of the channel length for the narrowest channel Table 3-a and largest channel Table 3-b on the PP replicas in comparison with dimensions of corresponding ridges on the Si/SU-8 mould insert.

	Middle	Extremity	Middle	Extremity
(a) Narrowest channel				
h [μm]	25 ± 1	25 ± 1	24 ± 1	24 ± 1
e_1 [μm]	25 ± 3	25 ± 3	29 ± 3	27 ± 3
e_2 [μm]	25 ± 3	25 ± 3	27 ± 3	26 ± 3
(b) Largest channel				
h [μm]	25 ± 1	25 ± 1	25 ± 1	25 ± 1
e_1 [μm]	400 ± 3	400 ± 3	409 ± 3	407 ± 3
e_2 [μm]	400 ± 3	400 ± 3	405 ± 3	402 ± 3

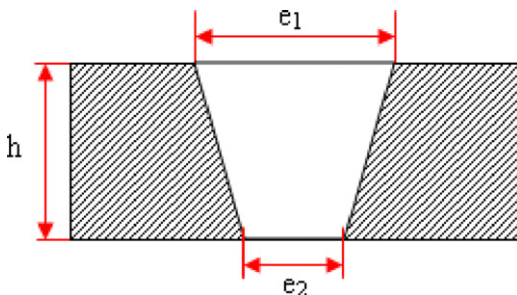


Fig. 4. Schematic of the channel cross-section indicating the depth (h), the width at the top and bottom of the channel, respectively (e_1 and e_2 , respectively).

areas (a and b) of the SU-8/Si mould insert and PP replicas were measured as indicated in Fig. 5.

Table 4 summarizes the roughness coefficients of these measured surfaces, the arithmetical average height, the root mean square height, and the total height (R_a , R_q and R_t , respectively) on the SU-8 mould insert and PP replica. The roughness factors ($R_{\text{replica}}/R_{\text{mould insert}}$), as determined from measurements in area (a) and (b) respectively, are also indicated in Table 4. Ideally, if the replication process reproduces perfectly well the roughness of the mould insert, the roughness of the replica should be equal to the roughness of the mould insert and the roughness factor should be equal to 1. In this case, the high value of the roughness ratios indicates that the replication process under the selected operative conditions does not reproduce faithfully the mould insert roughness, in particular in the areas corresponding to the microstructures of the mould insert. A decrease of those ratios can be achieved by using a higher temperature for injection moulding and mould temperature, which will decrease the viscosity of the PP polymer, hence fill better the microcavities of the mould insert.

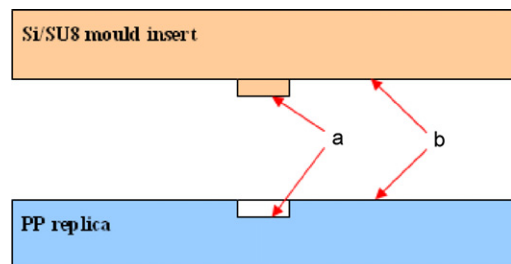


Fig. 5. Schematic representation of the mould insert and replica with the different areas measured (a and b).

Table 4

Roughness coefficients and roughness ratios of the various surfaces measured in the areas indicated in Fig. 5.

	Mould insert		PP replica		$R_{\text{replica}}/R_{\text{insert}}$	
	Area a	Area b	Area a	Area b	Area a	Area b
Arithmetical mean roughness (R_a in nm)	1	6	45	58	45	9.7
Root mean square roughness (R_q in nm)	1.3	8	56	72	43.1	9
Maximum peak-to-valley roughness (R_t in nm)	15	70	524	701	34.9	10

Table 5

Results in injection moulding various thermoplastic polymers using photolithographically defined SU-8/Si mould inserts.

Injection moulding	PP (EP548N, Basel)	PP (RA12MN40, Sabcic)	COC (8007, TOPAS)	PMMA (Plexiglass, df21, 6N, Evonik)
Feature size: width (μm)/depth (μm)	25 μm to 400 μm /50 μm	25 μm to 100 μm /90 μm	25 to 100 μm /90 μm	25 to 100 μm /90 μm
Length of microstructure (mm)	30	30	30	30
Maximum aspect ratio (depth/width) obtained	2	3.6	3.6	3.6
Thickness of replica (μm)	500	320	770	780
Number of replicas	30	>100	20	20

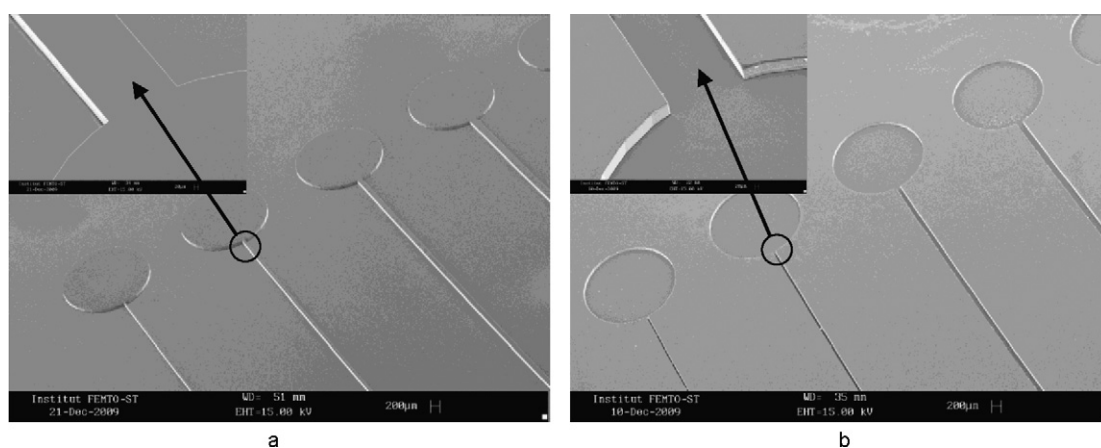


Fig. 6. Microfeatures of 50 μm , 75 μm , 100 μm to 150 μm width (from left to right) and 90 μm height on (a): SU-8/Si mould insert (ridges) and on (b): PP (Sabcic) replica (channels). The insets of pictures (a) and (b) correspond to magnified views (SEM pictures) at the extremities of 75 μm wide ridge and channel, respectively, as indicated by the arrows.

3.3. Replication in thermoplastic polymers

Injection moulding was conducted using various thermoplastic polymers. Table 5 summarizes the various replicas injection-moulded in PP, COC and PMMA using SU-8/Si mould inserts. The feature size and length of microstructures on the mould, the thickness of polymer replicas and the number of replications performed without deterioration of the mould is also indicated in

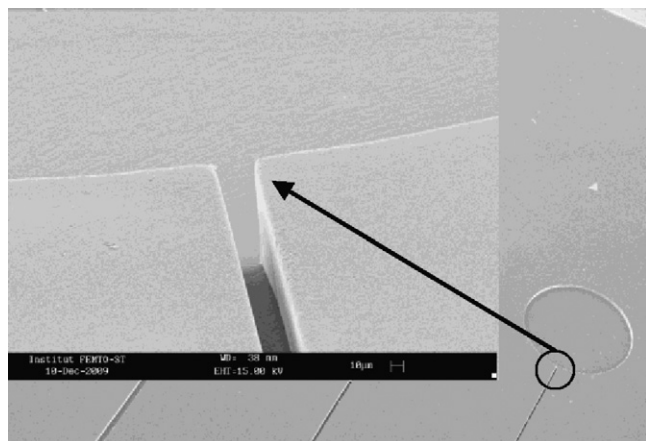


Fig. 7. SEM image of a micro-channel (25 μm width, 90 μm height) in PP (Sabcic) replica; inset: magnified view of the microchannel (indicated by the arrow).

this table. Flash could be seen only on the border of the replica wafer plate, but not in the central part. Quality of replicas was found to be good all along the length of the channels.

Fig. 6 represents the SEM images of a PP replica with microchannels of various widths (from 50 μm to 150 μm) and 90 μm depth along with the reverse pattern on the SU-8/Si mould insert. Fig. 7 shows the minimum feature size that was produced (25 μm width in 90 μm height). The channel exhibits nearly vertical sidewalls.

A number of replicas largely sufficient for prototyping needs were produced successfully without deterioration of the SU-8/Si mould using PP (Sabcic). The process developed was used for prototyping disposable thin PP microfluidic biochips designed for protein crystallization and analysis [9,10].

COC and PMMA replicas were fabricated by using the mould insert with high aspect ratio (3.6). Demoulding of the replicas in both COC and PMMA proved more difficult as compared with PP, with COC the most difficult to demould. The greater brittleness and stiffness of PMMA and COC appear to be a sensitive parameter influencing the quality of replicas when demoulding manually; PMMA and COC have an elastic modulus higher than PP (a factor 2 as can be seen in Table 1), which results in breaking the parts if demoulding is conducted at room temperature. Therefore in our experiments, the demoulding was performed at a relatively high temperature, around 75 $^{\circ}\text{C}$ for COC and 45 $^{\circ}\text{C}$ for PMMA. In these conditions, good quality of replicas was obtained for PMMA, even with the smallest feature size (25 μm) as can be seen in Figs. 8 and

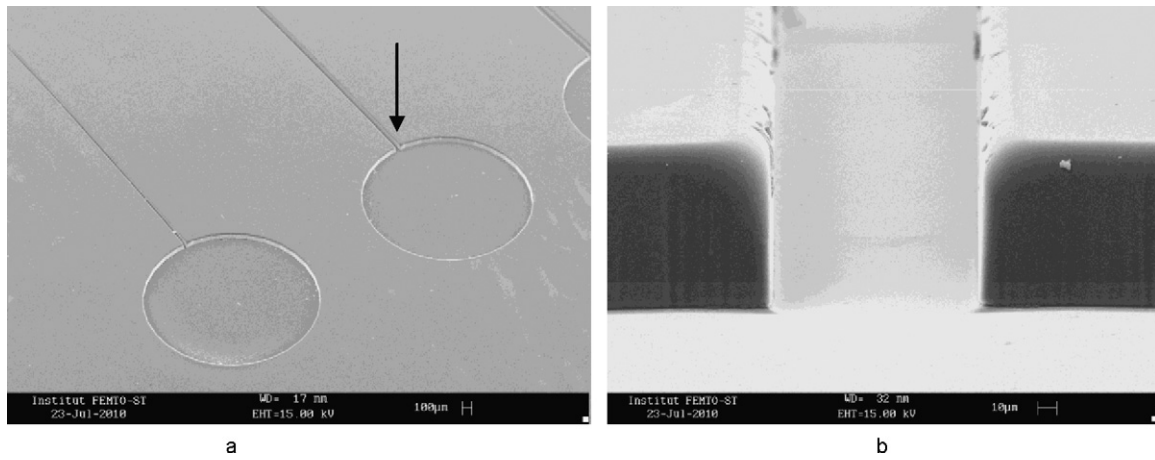


Fig. 8. SEM image of PMMA replica using a SU-8/Si mould insert; (a): channels with reservoir; (b) blown-up view of channel entrance (100 μm width and 100 μm height) as indicated by the arrow.

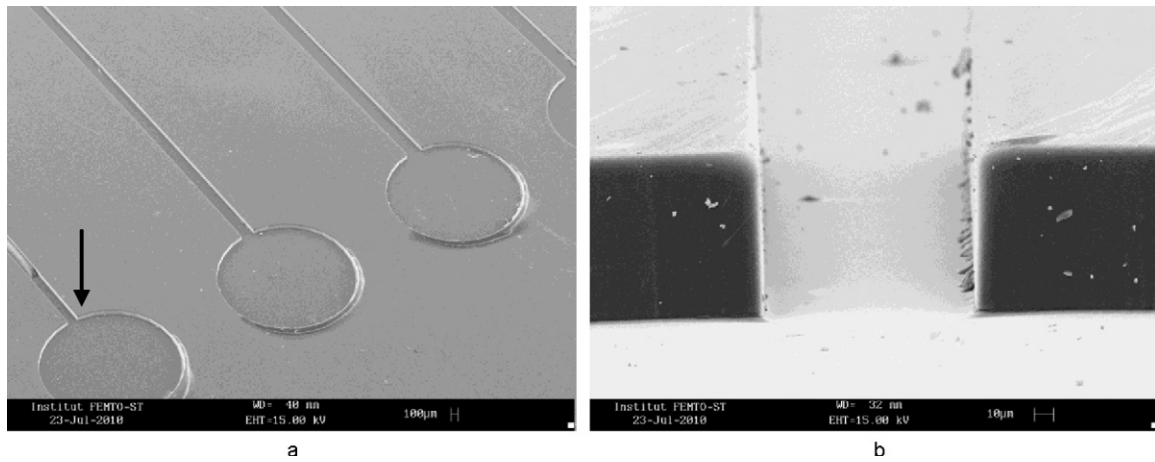


Fig. 9. SEM image of COC replica using a SU-8/Si mould insert; (a): channels with reservoir; (b) blown-up view of channel entrance (100 μm width and 100 μm height) as indicated by the arrow.

10a whereas this led to some defects in the COC parts, for example too much matter along the reservoir edges or in the smallest channel (25 μm) as well as surfaces less smooth as compared with PMMA (as can be seen on the SEM pictures of Figs. 9 and 10b). The temperature of demoulding for COC could not be increased any further as it is already close to the glass transition temperature of COC 8007 ($\sim 75^\circ\text{C}$ vs. 78°C) which already leads to pattern

deformation. Due to the higher forces required to demould the parts in both PMMA and COC as compared with PP, the adherence of SU-8 layer also becomes weaker resulting in tearing out of the long ridges on the mould insert. This explains the lower number of replicas produced in PMMA and COC as compared with PP (Table 5).

Two main sources of wear for microstructured features of the SU-8 mould insert have been identified: (1) during the injection

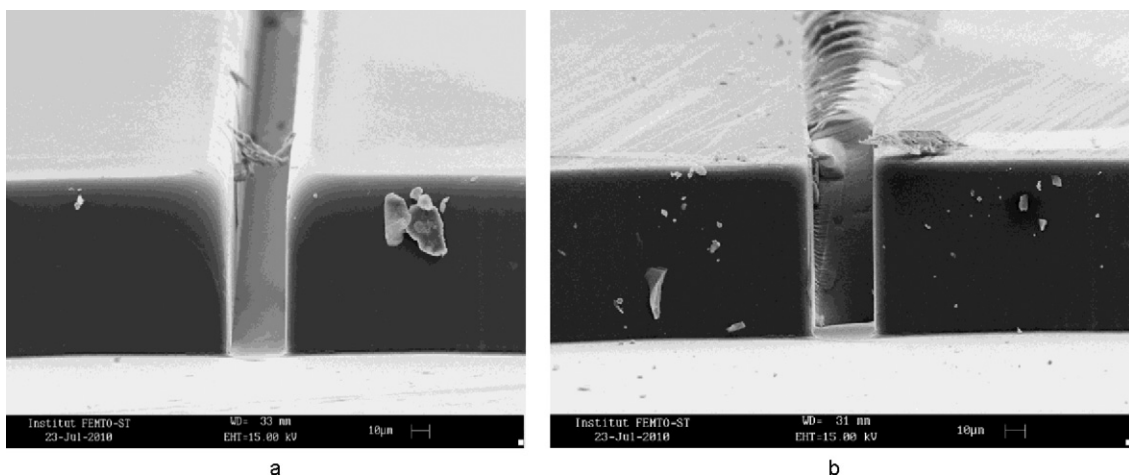


Fig. 10. SEM pictures of 25 μm wide feature with 90 μm height in PMMA (a) and COC (b).

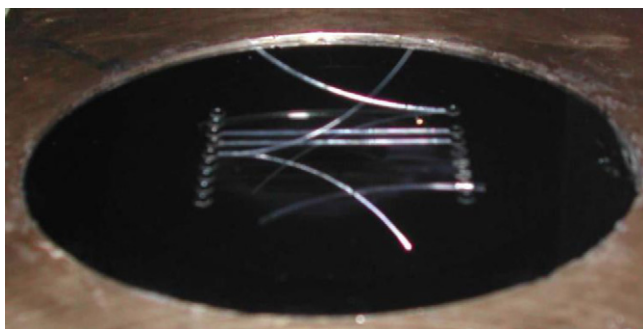


Fig. 11. Picture of the SU-8/Si mould insert with ridges of 30 mm length and 100 μm width and height destroyed after demoulding.

moulding process, the resistance of the patterns of the mould insert to the hydrodynamical forces exerted by the melt polymer during the filling of the cavity; (2) during the demoulding step, the issues of adherence and friction between the mould insert and replica, which may cause the tearing of very long and tall ridges of aspect ratio superior to 1. SU-8 ridges of 30 mm length and 100 μm width and height on the mould insert were destroyed as could be observed after the demoulding step (Fig. 11).

4. Conclusions

Rapid manufacturing of low-cost exchangeable high resolution mould inserts for high precision injection moulding of polymer chips was developed. The processes developed were based on using thick silicon wafers which were patterned using the SU-8 negative resist.

Using SU-8 resist allows producing mould inserts with a very wide range of feature sizes, with scale from microscale to nanoscale using two different processes and clean room technologies, photolithography and electron-beam lithography, respectively.

The main results obtained in this work are the following:

- Mould inserts with microscopic features were produced in SU-8 by contact photolithography using a two-step coating process. The mould inserts were implemented on a standard injection moulding machine.
- Injection moulding tests conducted using polypropylene (PP) polymer showed good replication quality with SU-8 microstructures of 90 μm height and width down to 25 μm , i.e. an aspect ratio of 3.6. The adherence of the SU-8 microstructures to the Si substrate was found to be adequate and the SU-8/Si mould inserts were robust enough to manufacture small series for lab purpose. In addition, a study of the PP parts was carried out using scanning mechanical microscopy (SMM) and scanning electron microscopy (SEM).
- Injection moulding of microstructures was also demonstrated on PMMA and COC, but demoulding was more difficult than for PP due to the greater brittleness and stiffness of these thermoplastics compared with PP, hence leading to a lower number of replicas produced without damaging the SU-8 mould inserts.
- Concerning the generation of submicronic features, patterning of the mould insert was performed using electron-beam lithography. Replication of submicronic features (500 nm) was demonstrated in PP.

The processes developed to manufacture SU-8 features on silicon based tools with feature size ranging from hundreds of micrometers

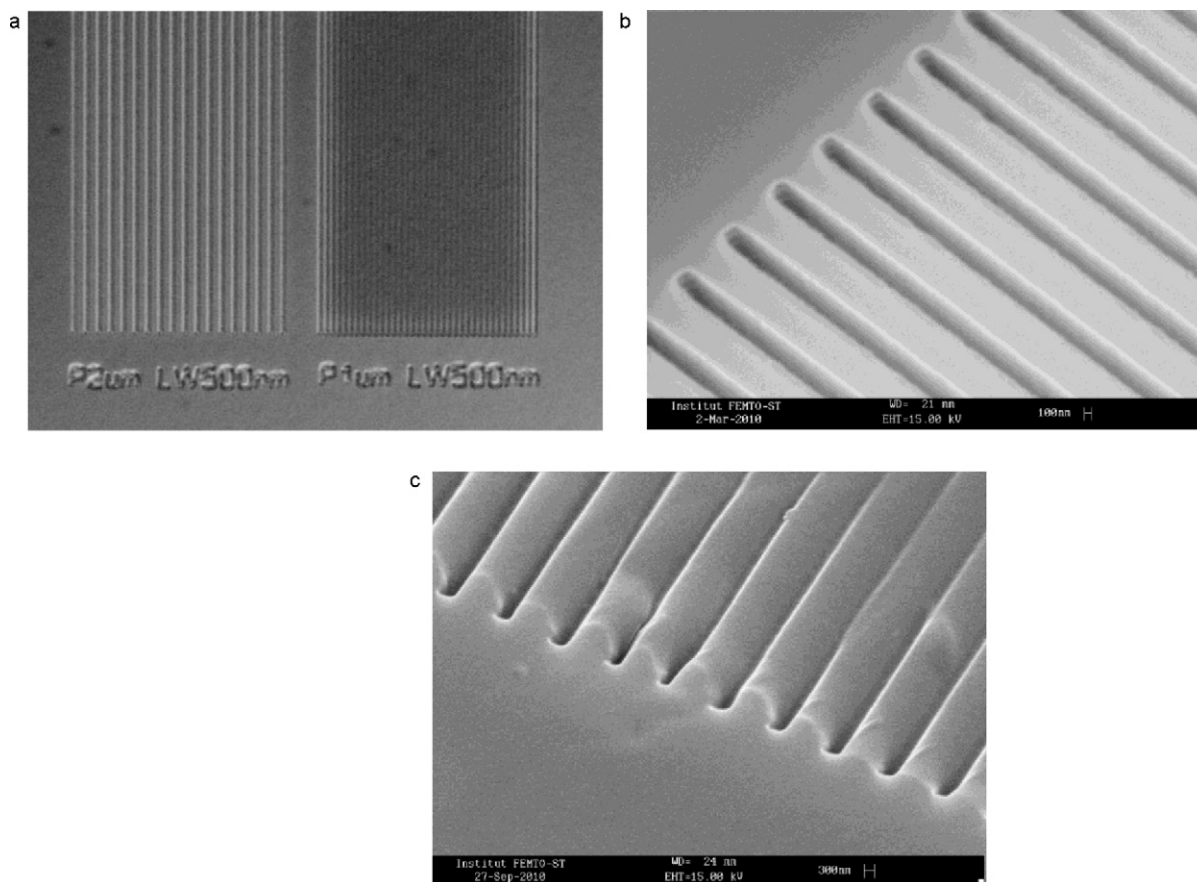


Fig. 12. Submicronic features on SU-8/Si mould insert and replica; (a) optical image of the arrays with ridges of 500 nm width and 2 μm pitch (left hand side of photograph); SEM pictures of submicronic feature on SU-8/Si mould insert (b) and PP replica (c) with array of 2 μm pitch and 500 nm wide ridges (in SU-8 on mould insert) or trenches (on PP replica).

to hundreds of nanometers using clean room technologies are adapted for prototyping needs and in some cases for small series as well. They are competitive with existing processes targeting the same size range, that is mechanical micromachining or proximal probe writing techniques, respectively.

5. Outlook

First experiments of replication of submicronic features have been demonstrated using a SU-8/silicon mould insert produced by e-beam lithography. The same operation conditions were used for injection moulding of submicronic features as for injecting microscopic features. An example of replica with an array of 500 nm features transferred in PP (Sabic) is shown in Fig. 11 along with a detail of the SU-8/Si mould insert (Fig. 12a and b).

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